

Octal D-Type Flip-Flop with 3-State Output

MC74VHC574, MC74VHCT574A

The MC74VHC574/MC74VHCT574A is an advanced high speed CMOS octal flip-flop with 3-state output fabricated with silicon gate CMOS technology. The device achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input and an output enable input. When the output enable input is high, the eight outputs are in a high impedance state.

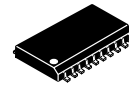
The MC74VHC574 inputs are compatible with standard CMOS levels while the MC74VHCT574A inputs are compatible with TTL levels. The MC74VHCT574A can be used as a level converter for interfacing 3.3 V to 5.0 V, because it has full 5.0 V CMOS level output swings.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The MC74VHC574 and MC74VHCT574A input structures tolerate voltages up to 5.5 V, allowing the interface of 5 V systems to 3 V systems.

The MC74VHCT574A output structures provide protection when $V_{CC} = 0$ V. These output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

Features

- High Speed: $f_{max} = 180$ MHz (Typ) at $V_{CC} = 5.0$ V
 $f_{max} = 140$ MHz (Typ) at $V_{CC} = 5.0$ V
- Low Power Dissipation: $I_{CC} = 4.0$ μ A (Max) at $T_A = 25^\circ$ C
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\%$
- Power Down Protection Provided
- Balanced Propagation Delays
- Designed for: 2.0 V to 5.5 V (VHC)
4.5 V to 5.5 V (VHCT)
- Low Noise: $V_{OLP} = 1.2$ V (Max) (VHC)
 $V_{OLP} = 1.6$ V (Max) (VHCT)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 100 mA
- ESD Performance: Human Body Model > 2000 V;
- Chip Complexity: 286 FETs or 71.5 Equivalent Gates
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

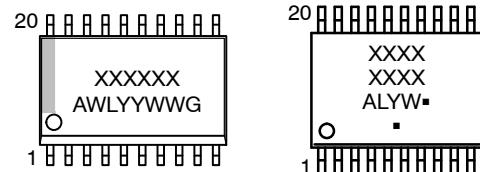


SOIC-20
DW SUFFIX
CASE 751D



TSSOP-20
DT SUFFIX
CASE 948E

MARKING DIAGRAMS



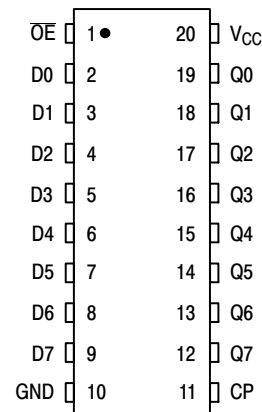
SOIC-20

TSSOP-20

- A = Assembly Location
- WL, L = Wafer Lot
- YY, Y = Year
- WW, W = Work Week
- G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN ASSIGNMENT



FUNCTION TABLE

INPUTS			OUTPUT
OE	CP	D	Q
L		H	H
L		L	L
L	L, H,	X	No Change
H	X	X	Z

ORDERING INFORMATION

See detailed ordering and shipping information on page 10 of this data sheet.

MC74VHC574, MC74VHCT574A

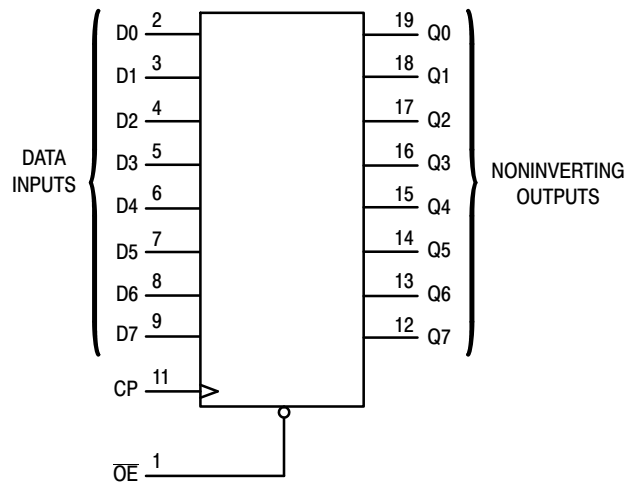


Figure 1. Logic Diagram

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V_{CC}	DC Supply Voltage	-0.5 to +6.5	V	
V_{IN}	DC Input Voltage	-0.5 to +6.5	V	
V_{OUT}	DC Output Voltage (MC74VHC)	-0.5 to $V_{CC} + 0.5$	V	
	DC Output Voltage (MC74VHCT)	Active Mode (High or Low State)		-0.5 to $V_{CC} + 0.5$
		Tristate Mode (Note 1)		-0.5 to +6.5
	Power-Off Mode ($V_{CC} = 0$ V)	-0.5 to +6.5		
I_{IN}	DC Input Current, per Pin	± 20	mA	
I_{OUT}	DC Output Current, Per Pin	± 25	mA	
I_{CC}	DC Supply Current, V_{CC} and GND Pins	± 75	mA	
I_{IK}	Input Clamp Current	-20	mA	
I_{OK}	Output Clamp Current	MC74VHC574	± 20	mA
		MC74VHCT574A	-20	
T_{STG}	Storage Temperature Range	-65 to +150	$^{\circ}$ C	
T_L	Lead Temperature, 1 mm from Case for 10 secs	260	$^{\circ}$ C	
T_J	Junction Temperature Under Bias	+150	$^{\circ}$ C	
θ_{JA}	Thermal Resistance (Note 2)	SOIC-20W	96	$^{\circ}$ C/W
		TSSOP-20	150	
P_D	Power Dissipation in Still Air at 25 $^{\circ}$ C	SOIC-20W	1302	mW
		TSSOP-20	833	
MSL	Moisture Sensitivity	Level 1	-	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.574 in	-
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	N/A	
$I_{LATCHUP}$	Latchup Performance (Note 4)	± 100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
4. Tested to EIA/JESD78 Class II.

MC74VHC574, MC74VHCT574A

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
MC74VHC				
V_{CC}	DC Supply Voltage	2.0	5.5	V
V_{IN}	DC Input Voltage (Note 5)	0	5.5	V
V_{OUT}	DC Output Voltage (Note 5)	0	V_{CC}	V
T_A	Operating Temperature	-40	+85	°C
t_r, t_f	Input Rise or Fall Rate	$V_{CC} = 3.0\text{ V to }3.6\text{ V}$ $V_{CC} = 4.5\text{ V to }5.5\text{ V}$	0 100	ns/V

MC74VHCT

V_{CC}	DC Supply Voltage	4.5	5.5	V	
V_{IN}	DC Input Voltage (Note 5)	0	5.5	V	
V_{OUT}	DC Output Voltage (Note 5)	Active Mode (High or Low State) Tristate Mode Power-Off Mode ($V_{CC} = 0\text{ V}$)	0 0 0	V_{CC} 5.5 5.5	V
T_A	Operating Temperature	-40	+85	°C	
t_r, t_f	Input Rise or Fall Rate	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

5. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (MC74VHC574)

Symbol	Parameter	Test Conditions	V_{CC} V	$T_A = 25^\circ\text{C}$			$T_A = -40\text{ to }85^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	
V_{IH}	Minimum High-Level Input Voltage		2.0 3.0 to 5.5	1.50 $V_{CC} \times 0.7$			1.50 $V_{CC} \times 0.7$		V
V_{IL}	Maximum Low-Level Input Voltage		2.0 3.0 to 5.5			0.50 $V_{CC} \times 0.3$		0.50 $V_{CC} \times 0.3$	V
V_{OH}	Minimum High-Level Output Voltage	$V_{in} = V_{IH}$ or V_{IL} $I_{OH} = -50\ \mu\text{A}$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
		$V_{in} = V_{IH}$ or V_{IL} $I_{OH} = -4\text{ mA}$ $I_{OH} = -8\text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		
V_{OL}	Maximum Low-Level Output Voltage	$V_{in} = V_{IH}$ or V_{IL} $I_{OL} = 50\ \mu\text{A}$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{in} = V_{IH}$ or V_{IL} $I_{OL} = 4\text{ mA}$ $I_{OL} = 8\text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44	
I_{in}	Maximum Input Leakage Current	$V_{in} = 5.5\text{ V}$ or GND	0 to 5.5			± 0.1		± 1.0	μA
I_{OZ}	Maximum Three-State Leakage Current	$V_{in} = V_{IL}$ or V_{IH} $V_{out} = V_{CC}$ or GND	5.5			± 0.25		± 2.5	μA
I_{CC}	Maximum Quiescent Supply Current	$V_{in} = V_{CC}$ or GND	5.5			4.0		40.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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AC ELECTRICAL CHARACTERISTICS (MC74VHC574)

Symbol	Parameter	Test Conditions	T _A = 25°C			T _A = - 40 to 85°C		Unit
			Min	Typ	Max	Min	Max	
f _{max}	Maximum Clock Frequency (50% Duty Cycle)	V _{CC} = 3.3 ± 0.3 V C _L = 15 pF	80	125	-	65	-	ns
		C _L = 50 pF	50	75	-	45	-	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CP to Q	V _{CC} = 3.3 ± 0.3 V C _L = 15 pF	-	8.5	13.2	1.0	15.5	ns
		C _L = 50 pF	-	11.0	16.7	1.0	19.0	
t _{PZL} , t _{PZH}	Output Enable Time, OE to Q	V _{CC} = 5.0 ± 0.5 V C _L = 15 pF	-	5.6	8.6	1.0	10.0	ns
		C _L = 50 pF	-	7.1	10.6	1.0	12.0	
t _{PZL} , t _{PZH}	Output Enable Time, OE to Q	V _{CC} = 3.3 ± 0.3 V C _L = 15 pF	-	8.2	12.8	1.0	15.0	ns
		C _L = 50 pF	-	10.7	16.3	1.0	18.5	
t _{PLZ} , t _{PHZ}	Output Disable Time, OE to Q	V _{CC} = 5.0 ± 0.5 V C _L = 15 pF	-	5.9	9.0	1.0	10.5	ns
		C _L = 50 pF	-	7.4	11.0	1.0	12.5	
t _{OSLH} , t _{OSHL}	Output to Output Skew	V _{CC} = 3.3 ± 0.3 V C _L = 50 pF (Note 6)	-	-	1.5	-	1.5	ns
		V _{CC} = 5.0 ± 0.5 V C _L = 50 pF (Note 6)	-	-	1.0	-	1.0	ns
C _{in}	Maximum Input Capacitance		-	4	10	-	10	pF
C _{out}	Maximum Three-State Output Capacitance, Output in High-Impedance State		-	6	-	-	-	pF

C _{PD}	Power Dissipation Capacitance (Note 7)	Typical @ 25°C, V _{CC} = 5.0 V		pF
		28		

6. Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.

7. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/8 (per flip-flop). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

MC74VHC574, MC74VHCT574A

NOISE CHARACTERISTICS (MC74VHC574) ($C_L = 50 \text{ pF}$, $V_{CC} = 5.0 \text{ V}$)

Symbol	Parameter	$T_A = 25^\circ\text{C}$		Unit
		Typ	Max	
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	0.9	1.2	V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	-0.9	-1.2	V
V_{IHD}	Minimum High Level Dynamic Input Voltage	-	3.5	V
V_{ILD}	Maximum Low Level Dynamic Input Voltage	-	1.5	V

TIMING REQUIREMENTS (MC74VHC574)

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$		$T_A = -40$ to 85°C	Unit
			Typ	Limit	Limit	
t_{su}	Minimum Setup Time, D to CP	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \pm 0.5 \text{ V}$	-	3.5	3.5	ns
t_h	Minimum Hold Time, CP to D	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \pm 0.5 \text{ V}$	-	1.5	1.5	ns
t_w	Minimum Pulse Width, CP	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \pm 0.5 \text{ V}$	-	5.0	5.5	ns

MC74VHC574, MC74VHCT574A

DC ELECTRICAL CHARACTERISTICS (MC74VHCT574A)

Symbol	Parameter	Test Conditions	V _{CC} V	T _A = 25°C			T _A = -40 to 85°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	Minimum High-Level Input Voltage		4.5 to 5.5	2.0			2.0		V
V _{IL}	Maximum Low-Level Input Voltage		4.5 to 5.5			0.8		0.8	V
V _{OH}	Minimum High-Level Output Voltage V _{in} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	4.5		4.4		V
		I _{OH} = -8 mA	4.5	3.94			3.80		
V _{OL}	Maximum Low-Level Output Voltage V _{in} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5		0.0	0.1		0.1	V
		I _{OL} = 8 mA	4.5			0.36		0.44	
I _{in}	Maximum Input Leakage Current	V _{in} = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μA
I _{OZ}	Maximum 3-State Leakage Current	V _{in} = V _{IL} or V _{IH} V _{out} = V _{CC} or GND	5.5			±0.25		±2.5	μA
I _{CC}	Maximum Quiescent Supply Current	V _{in} = V _{CC} or GND	5.5			4.0		40.0	μA
I _{CCT}	Quiescent Supply Current	Per Input: V _{IN} = 3.4 V Other Input: V _{CC} or GND	5.5			1.35		1.50	mA
I _{OPD}	Output Leakage Current	V _{OUT} = 5.5 V	0			0.5		5.0	μA

AC ELECTRICAL CHARACTERISTICS (MC74VHCT574A)

Symbol	Parameter	Test Conditions	T _A = 25°C			T _A = -40 to 85°C		Unit
			Min	Typ	Max	Min	Max	
f _{max}	Maximum Clock Frequency (50% Duty Cycle)	V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF	90 85	140 130		80 95		MHz
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CP to Q	V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF		4.1 5.6	9.4 10.4	1.0 1.0	10.5 11.5	ns
t _{PZL} , t _{PZH}	Output Enable Time, OE to Q	V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF		6.5 7.3	10.2 11.2	1.0 1.0	11.5 12.5	ns
t _{PLZ} , t _{PHZ}	Output Disable Time, OE to Q	V _{CC} = 5.0 ± 0.5 V C _L = 50 pF		7.0	11.2	1.0	12.0	ns
t _{OSLH} , t _{OSHL}	Output to Output Skew	V _{CC} = 5.0 ± 0.5 V C _L = 50 pF (Note 8)			1.0		1.0	ns
C _{in}	Maximum Input Capacitance			4	10		10	pF
C _{out}	Maximum Three-State Output Capacitance, Output in High-Impedance State			9				pF

C _{PD}	Power Dissipation Capacitance (Note 9)	Typical @ 25°C, V _{CC} = 5.0 V		pF
		25		

8. Parameter guaranteed by design. t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|.
9. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}/8 (per flip-flop). C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

MC74VHC574, MC74VHCT574A

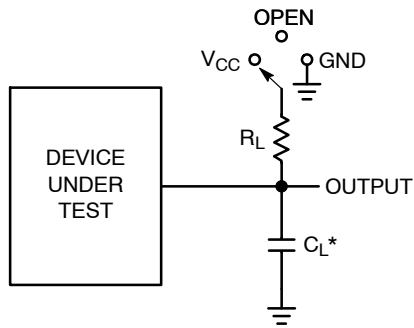
NOISE CHARACTERISTICS (MC74VHCT574A) ($C_L = 50 \text{ pF}$, $V_{CC} = 5.0 \text{ V}$)

Symbol	Parameter	$T_A = 25^\circ\text{C}$		Unit
		Typ	Max	
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	1.2	1.6	V
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	-1.2	-1.6	V
V_{IHD}	Minimum High Level Dynamic Input Voltage		2.0	V
V_{ILD}	Maximum Low Level Dynamic Input Voltage		0.8	V

TIMING REQUIREMENTS (MC74VHCT574A)

Symbol	Parameter	Test Conditions	$T_A = 25^\circ\text{C}$		$T_A = -40 \text{ to } 85^\circ\text{C}$	Unit
			Typ	Limit	Limit	
t_{su}	Minimum Setup Time, D to CP	$V_{CC} = 5.0 \pm 0.5 \text{ V}$		6.5	8.5	ns
t_h	Minimum Hold Time, CP to D	$V_{CC} = 5.0 \pm 0.5 \text{ V}$		2.5	2.5	ns
t_w	Minimum Pulse Width, CP	$V_{CC} = 5.0 \pm 0.5 \text{ V}$		2.5	2.5	ns

MC74VHC574, MC74VHCT574A



* C_L Includes probe and jig capacitance
Input signal $t_R = t_F = 3$ ns

Test	Switch Position	C_L	R_L
t_{PLH} / t_{PHL}	Open	See AC Characteristics Table	1 k Ω
t_{PLZ} / t_{PZL}	V_{CC}		
t_{PHZ} / t_{PZH}	GND		

Figure 2. Test Circuits

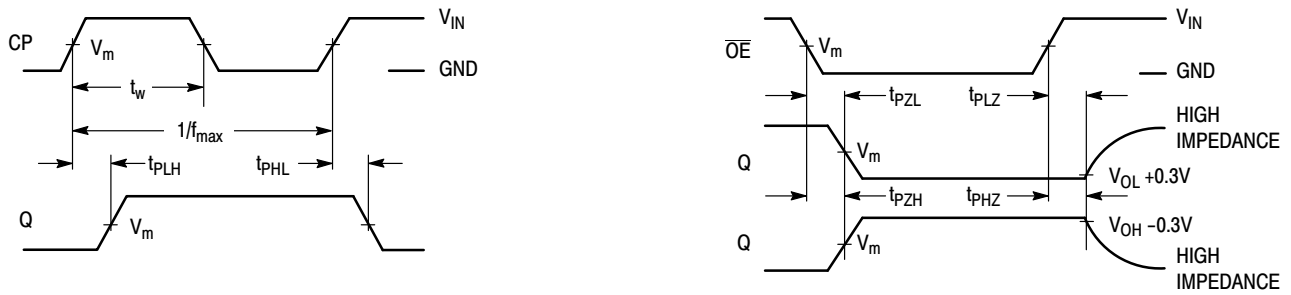


Figure 3. Switching Waveforms

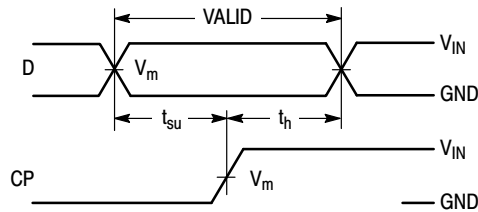


Figure 4.

Device	V_{IN}, V	V_m, V
MC74VHC574	V_{CC}	$50\% \times V_{CC}$
MC74VHCT574A	3 V	1.5 V

MC74VHC574, MC74VHCT574A

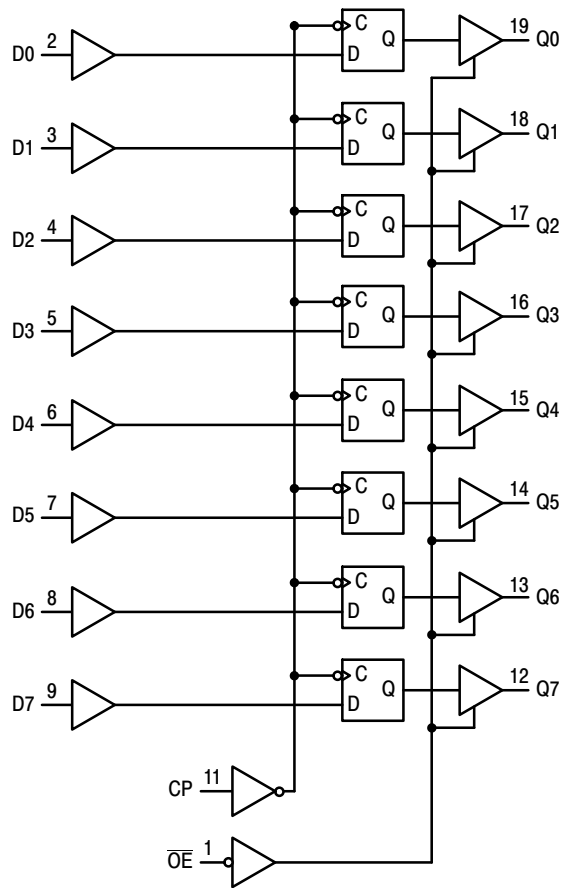


Figure 5. Expanded Logic Diagram

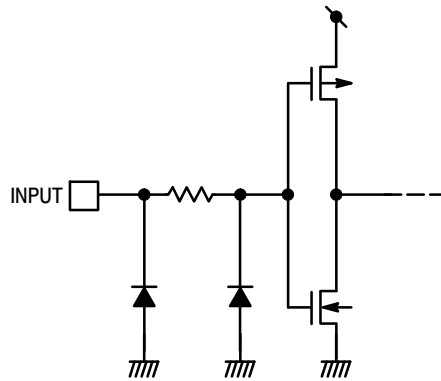


Figure 6. Input Equivalent Circuit

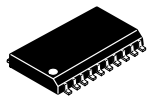
MC74VHC574, MC74VHCT574A

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74VHC574DWG	VHC574G	SOIC-20W	38 Units / Rail
MC74VHC574DWR2G	VHC574G	SOIC-20W	1000 / Tape & Reel
MC74VHC574DTG	VHC 574	TSSOP-20	75 Units / Rail
MC74VHC574DTR2G	VHC 574	TSSOP-20	2500 / Tape & Reel
MC74VHCT574ADWR2G	VHCT574AG	SOIC-20W	1000 / Tape & Reel
MC74VHCT574ADTR2G	VHCT 574A	TSSOP-20	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

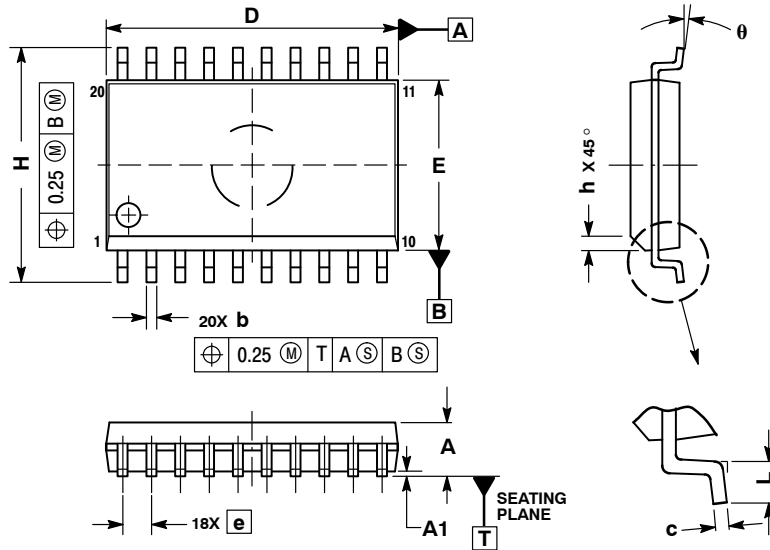
*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable



SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

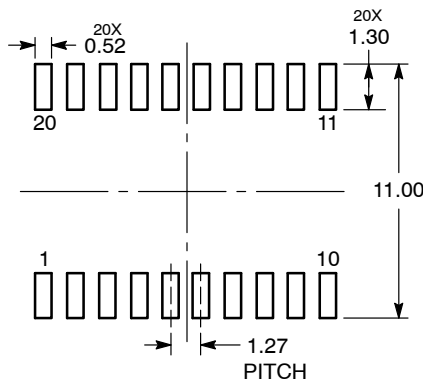


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

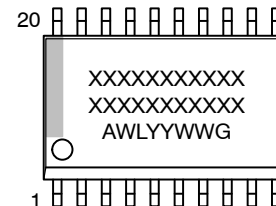
RECOMMENDED
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

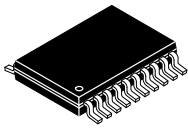
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

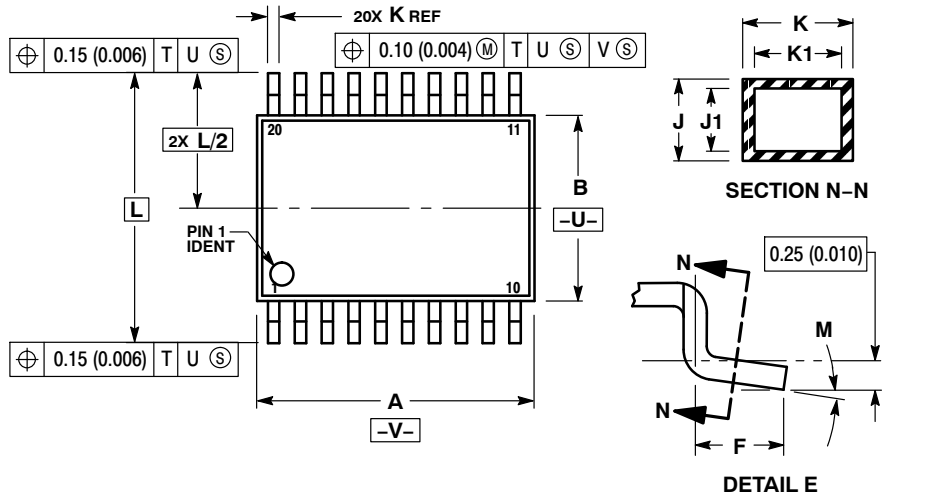
ON Semiconductor®



TSSOP-20 WB
CASE 948E
ISSUE D

DATE 17 FEB 2016

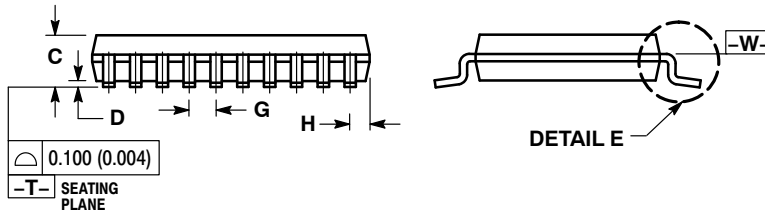
SCALE 2:1



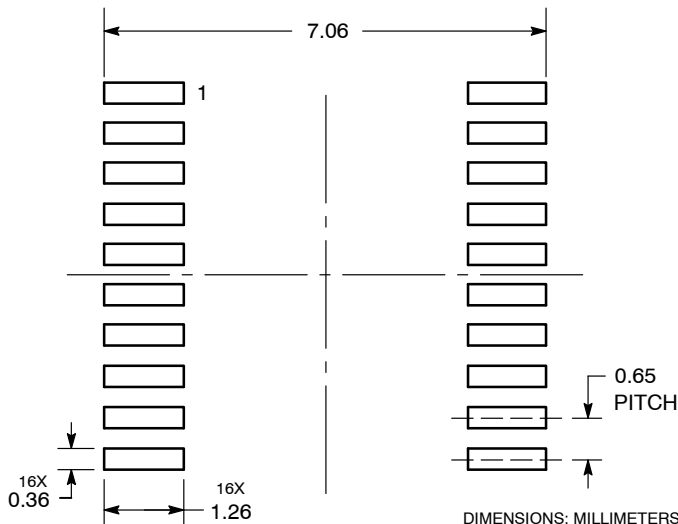
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

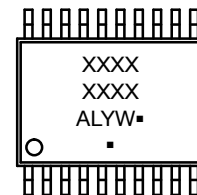
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°



SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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